

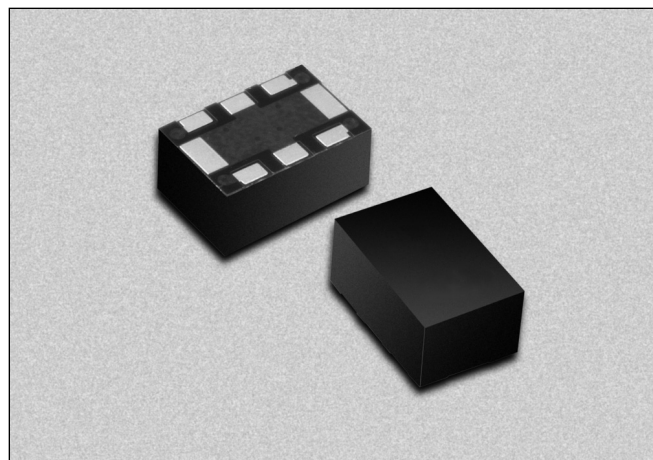
LGA Packaged Phase Shifter for AMPS Base Stations



PS088-315

Features

- Designed for AMPS 881.5 ± 12.5 MHz Band
- 100 Degree Phase Shift Range
- 1.5 Degree Phase Deviation
- 0.3 dB Insertion Loss Deviation
- 0–12 V Control Voltage Range
- Specified 33 dBm IP3
- Small Footprint LGA Package



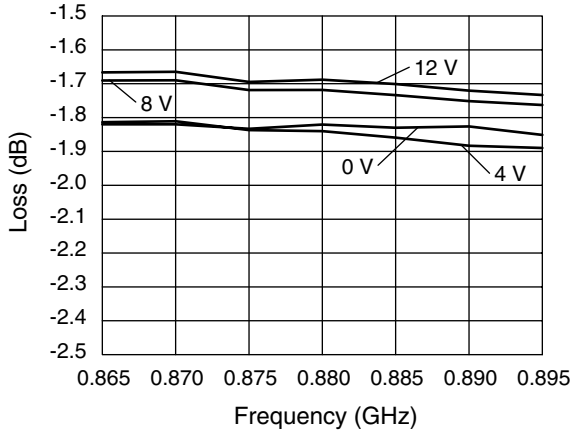
Description

The PS088-315 is a voltage controlled phase shifter designed for use in power amplifier distortion compensation circuits in AMPS band base station applications. Its characteristics are specified in a 25 MHz bandwidth centered at 881.5 MHz. The PS088-315 employs a monolithic quadrature hybrid and a pair of selected silicon varactor diodes to achieve 100 degree phase shift and low insertion loss. The PS088-315 is packaged in the small outline LGA (Land Grid Array) surface mount package with the internal elements affixed to an organic BT substrate.

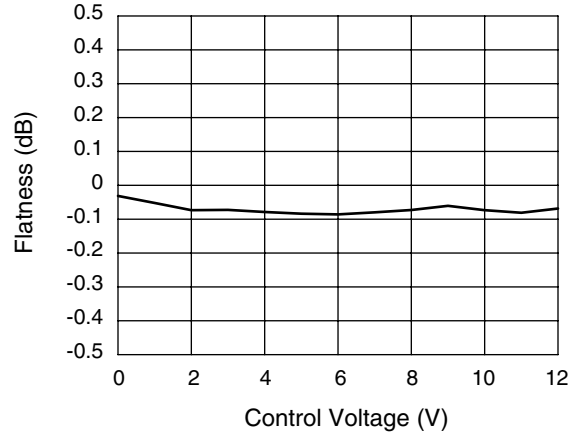
Electrical Specifications at 25°C

Parameter	Condition	Min.	Typ.	Max.	Unit
Frequency Range (BW)	$F_O = 881.5$	869		894	MHz
Phase Shift	At F_O , $C_V = 12$ V from $C_V = 0$ V	100			Deg.
Phase Deviation in BW	$C_V = 0-12$ V		1.5	2.0	Deg.
Control Voltage (C_V) Range		0		12	V
Control Current	$C_V = 12$ V			1	μ A
Insertion Loss in BW	$C_V = 0$ V			2.3	dB
I.L. Flatness in BW	$C_V = 0-12$ V			0.3	dB
I.L. Variation	At F_O , $C_V = 0-12$ V			0.75	dB
VSWR in BW				1.8	
IM3	$P_{IN} = 8$ dBm, 900/905 MHz, $C_V = 0$ V			-50	dBc
IP3	Derived from IM3	33			dBm

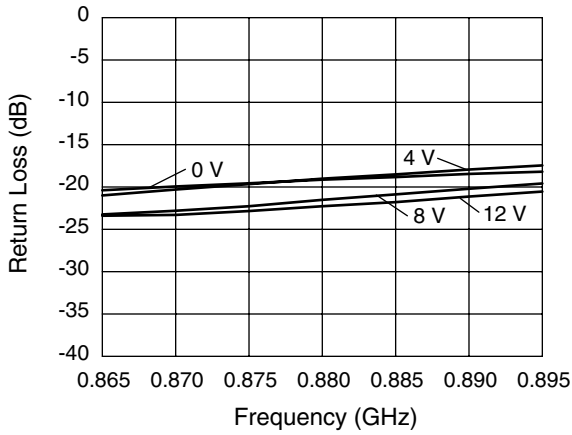
Typical Performance Data



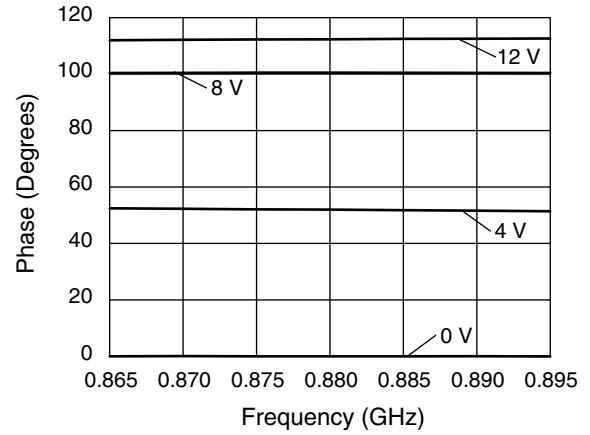
Insertion Loss vs. Frequency and Control Voltage



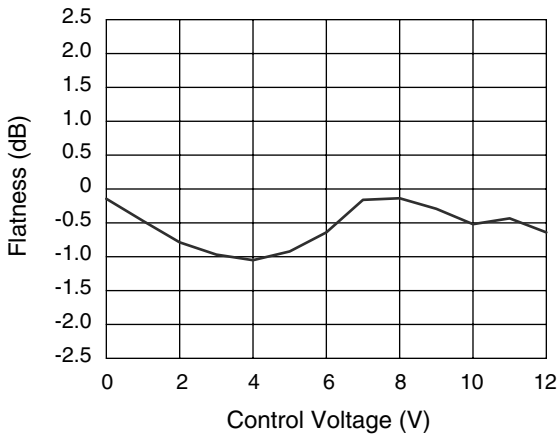
Insertion Loss Flatness vs. Control Voltage



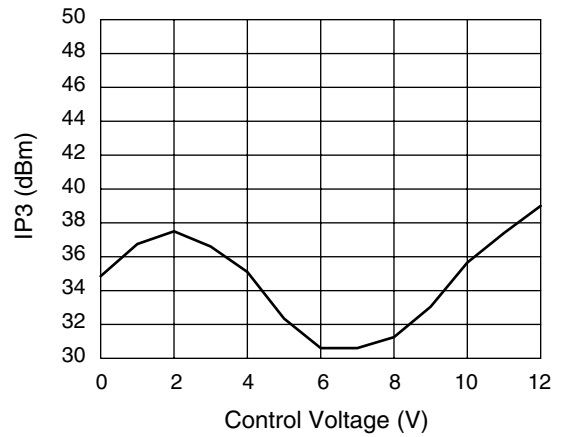
Input/Output Return Loss vs. Frequency and Control Voltage



Phase vs. Frequency and Control Voltage

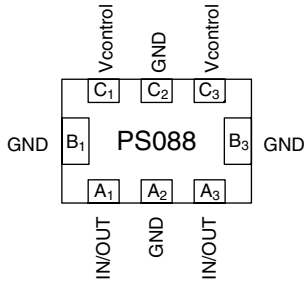


Phase Flatness vs. Control Voltage



IP3 vs. Control Voltage
 RF₁ = 0.900 GHz, RF₂ = 0.905 GHz @ 8 dBm

Pin Out (Bottom View)

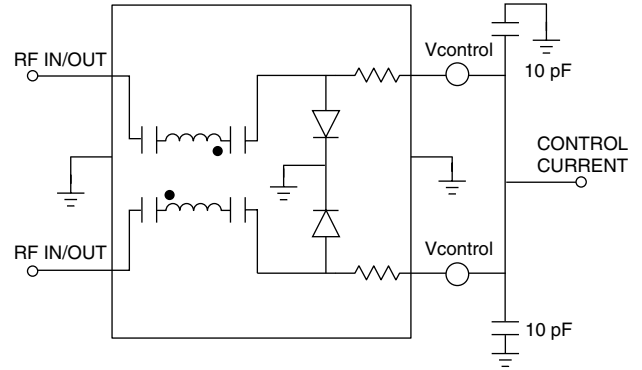


Terminal No.	Terminal Name
A ₁ (Pin 1)	IN/OUT
A ₂	GND
A ₃	IN/OUT
B ₁	GND
B ₃	GND
C ₁	Vcontrol
C ₂	GND
C ₃	Vcontrol

Absolute Maximum Ratings

Characteristic	Value
RF Input Power	20 dBm
Control Voltage	15 V
Operating Temperature	-40 to +85°C
Storage Temperature	-40 to +85°C
Electrostatic Discharge	HBM 1 B

Connection Diagram



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